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ULTRA FAST RECOVERY RECTIFIER DIODES



Glass-passivated, high-efficiency epitaxial rectifier diodes in DO-5 metal envelopes, featuring low forward voltage drop, ultra fast reverse recovery times, very low stored charge and soft recovery characteristic. They are intended for use in switched-mode power supplies and high-frequency circuits in general, where low conduction and switching losses are essential. The series consists of normal polarity (cathode to stud) types.

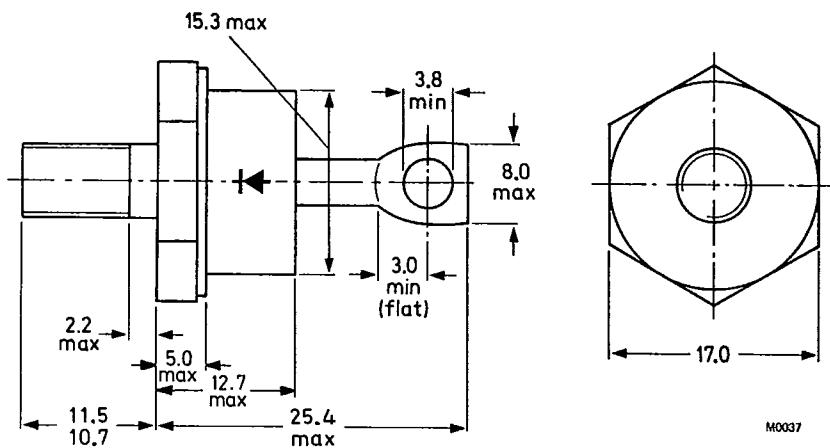
QUICK REFERENCE DATA

		BYW93-50	100	150	200	
Repetitive peak reverse voltage	V _{RRM}	max. 50	100	150	200	V
Average forward current	I _{F(AV)}	max.		60		A
Forward voltage	V _F	<		0.8		V
Reverse recovery time	t _{rr}	<		45		ns

MECHANICAL DATA

Dimensions in mm

Fig.1 DO-5; with metric M6 stud (ϕ 6 mm): e.g. BYW93-50
with $\frac{1}{4}$ in x 28 UNF stud (ϕ 6.35 mm); e.g. BYW93-50U



Net mass: 22 g

Supplied with device: 1 nut, 1 lock washer

Diameter of clearance hole: max. 6.5 mm

Torque on nut: min. 1.7 Nm (17 kg cm)

Accessories supplied on request:
see ACCESSORIES section.

max. 3.5 Nm (35 kg cm)

Nut dimensions across the flats: M6: 10 mm,
 $\frac{1}{4}$ in x 28 UNF: 11.1 mm

Products approved to CECC 50 009-028, available on request.

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RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134).

Voltages	BYW93-50	100	150	200	
Repetitive peak reverse voltage	V_{RRM}	max. 50	100	150	200 V
Crest working reverse voltage	V_{RWM}	max. 50	100	150	200 V
Continuous reverse voltage*	V_R	max. 50	100	150	200 V

Currents

Average forward current; switching losses negligible up to 500 kHz

square wave; $\delta = 0.5$; up to $T_{mb} = 110^\circ C$	$I_{F(AV)}$	max.	60	A
up to $T_{mb} = 125^\circ C$	$I_{F(AV)}$	max.	40	A
sinusoidal; up to $T_{mb} = 115^\circ C$	$I_{F(AV)}$	max.	50	A
up to $T_{mb} = 125^\circ C$	$I_{F(AV)}$	max.	38	A

R.M.S. forward current	$I_{F(RMS)}$	max.	85	A
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Repetitive peak forward current	I_{FRM}	max.	1500	A
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half sine-wave; $T_j = 150^\circ C$ prior to surge;	I_{FSM}	max.	800	A
with reapplied V_{RWMmax}	I_{FSM}	max.	1000	A

I^2t for fusing ($t = 10$ ms)	I^2t	max.	3200	A^2s
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Temperatures

Storage temperature	T_{stg}	-55 to +150	$^\circ C$
Junction temperature	T_j	max.	150 $^\circ C$

THERMAL RESISTANCE

From junction to mounting base	$R_{th j-mb}$	=	0.7	K/W
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From mounting base to heatsink	$R_{th mb-h}$	=	0.2	K/W
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a. with heatsink compound	$R_{th mb-h}$	=	0.3	K/W
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b. without heatsink compound	$R_{th mb-h}$	=	0.32	K/W
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Transient thermal impedance; $t = 1$ ms	$Z_{th j-mb}$	=	0.32	K/W
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MOUNTING INSTRUCTIONS

The top connector should be neither bent nor twisted; it should be soldered into the circuit so that there is no strain on it.

During soldering the heat conduction to the junction should be kept to a minimum.

*To ensure thermal stability: $R_{th j-a} \leq 3.0$ K/W.

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CHARACTERISTICS

Forward voltage

$I_F = 50 \text{ A}; T_j = 150^\circ\text{C}$
 $I_F = 150 \text{ A}; T_j = 25^\circ\text{C}$

V_F	<	0.8	V^*
V_F	<	1.3	V^*

Reverse current

$V_R = V_{RWM \text{ max}}; T_j = 100^\circ\text{C}$
 $T_j = 25^\circ\text{C}$

I_R	<	5	mA
I_R	<	250	μA

Reverse recovery when switched from

$I_F = 1 \text{ A}$ to $V_R \geq 30 \text{ V}$ with $-dI_F/dt = 100 \text{ A}/\mu\text{s}$;
 $T_j = 25^\circ\text{C}$; recovery time

t_{rr}	<	45	ns
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$I_F = 2 \text{ A}$ to $V_R \geq 30 \text{ V}$ with $-dI_F/dt = 20 \text{ A}/\mu\text{s}$
 $T_j = 25^\circ\text{C}$; recovered charge

Q_s	<	35	nC
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$I_F = 10 \text{ A}$ to $V_R \geq 30 \text{ V}$ with $-dI_F/dt = 50 \text{ A}/\mu\text{s}$;
 $T_j = 100^\circ\text{C}$; peak recovery current

I_{RRM}	<	6	A
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Forward recovery when switched to $I_F = 10 \text{ A}$
with $dI_F/dt = 10 \text{ A}/\mu\text{s}$; $T_j = 25^\circ\text{C}$

V_{fr}	typ.	1.0	V
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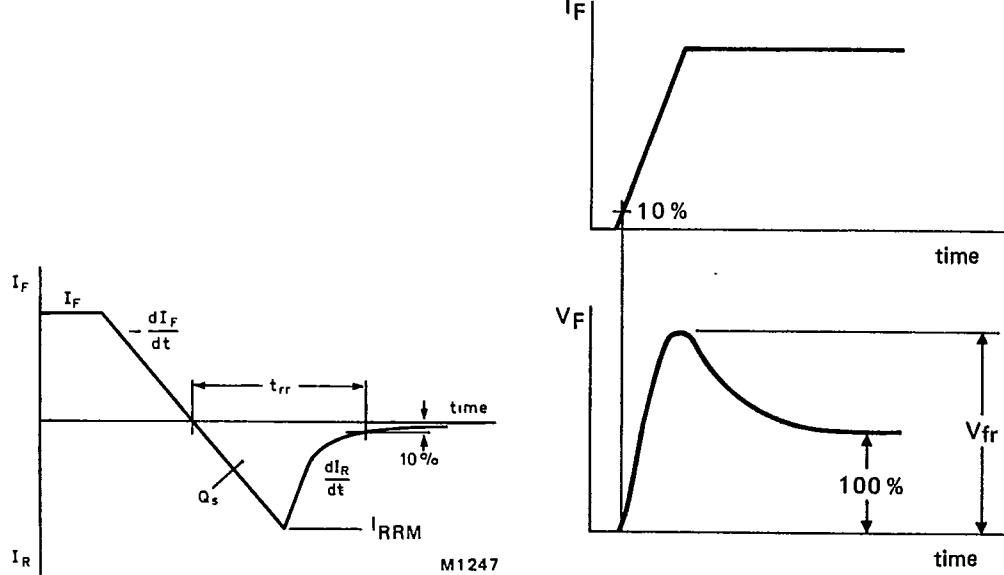


Fig.2 Definition of t_{rr} , Q_s and I_{RRM} .

Fig.3 Definition of V_{fr} .

*Measured under pulse conditions to avoid excessive dissipation.

SQUARE-WAVE OPERATION

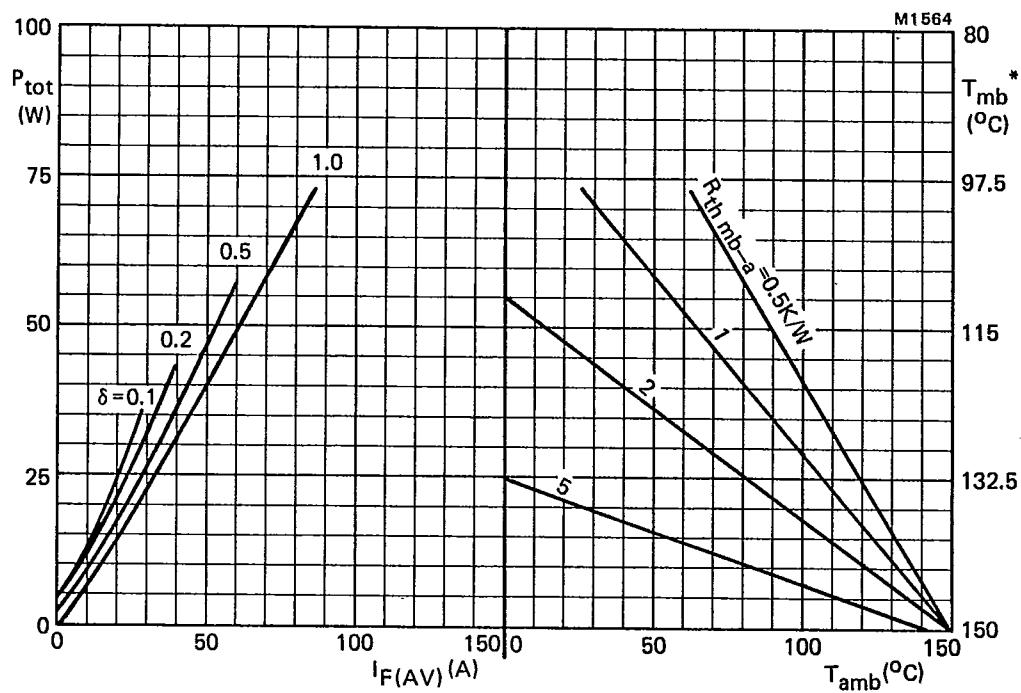
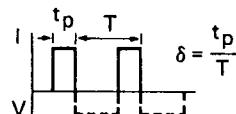


Fig.4 The right-hand part shows the interrelationship between the power (derived from the left-hand part) and the maximum permissible temperatures.

Power includes reverse current losses.



$$I_F(AV) = I_F(\text{RMS}) \times \sqrt{\delta}$$

* T_{mb} scale is for comparison purposes and is correct only for $R_{th\ mb-a} < 2.1\text{ K/W}$

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SINUSOIDAL OPERATION

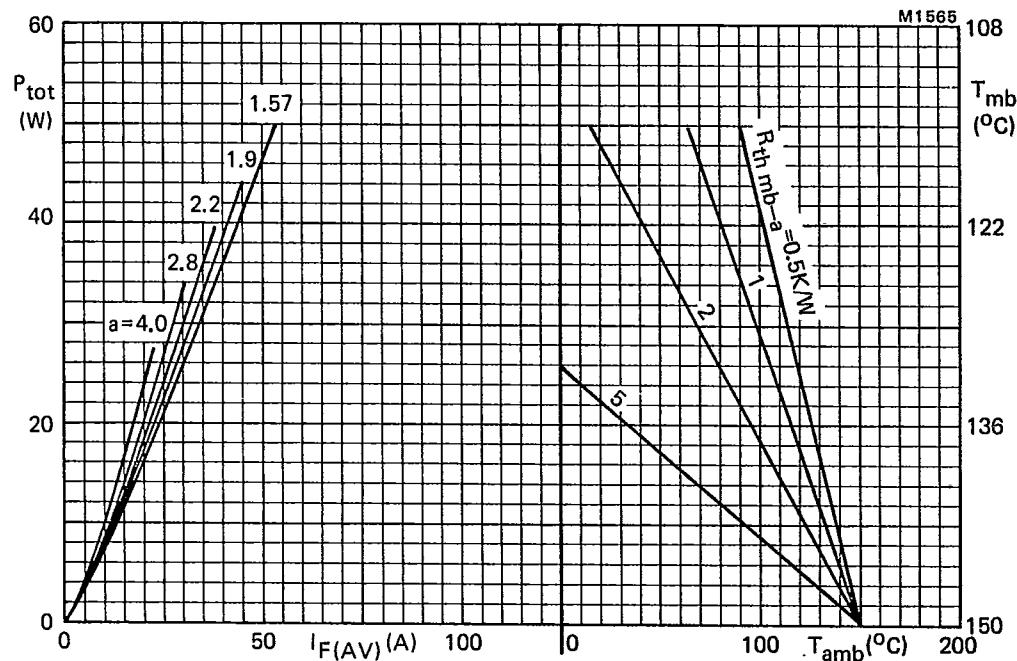


Fig.5 The right-hand part shows the interrelationship between the power (derived from the left-hand part) and the maximum permissible temperatures.

Power includes reverse current losses.

$$a = \text{form factor} = I_F(\text{RMS})/I_F(\text{AV}).$$

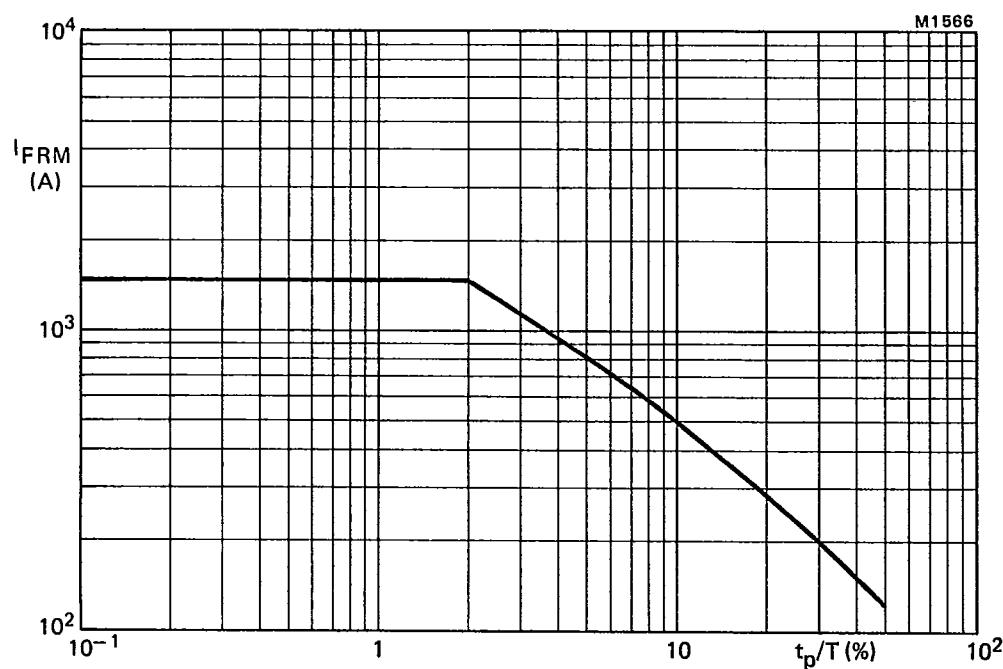


Fig.6 Maximum permissible repetitive peak forward current for square or sinusoidal currents;
 $1 \mu\text{s} < t_p < 1 \text{ ms.}$

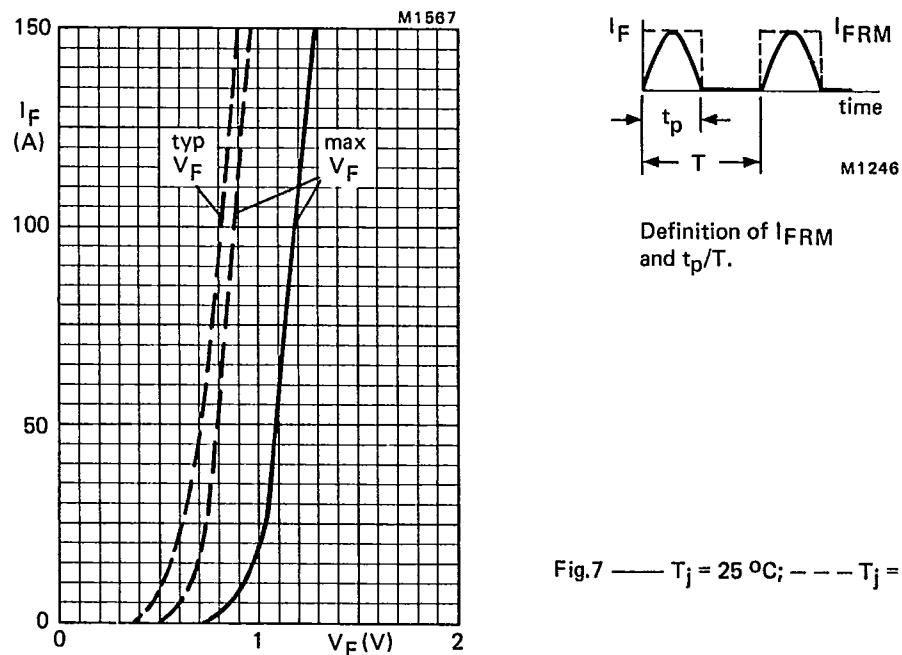


Fig.7 — $T_j = 25^\circ\text{C}$; $-- T_j = 150^\circ\text{C}$.

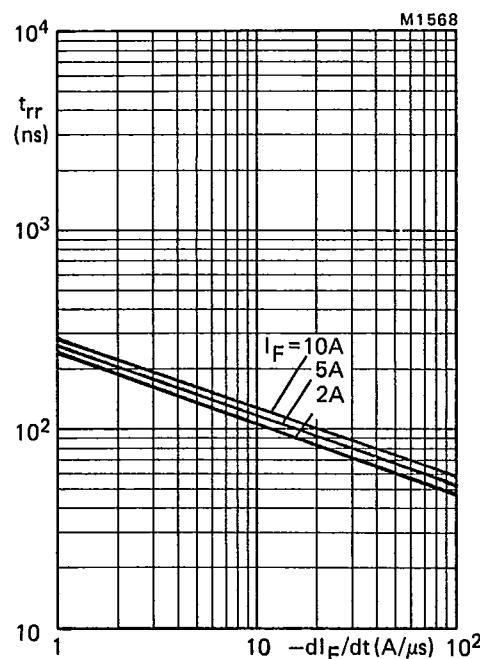


Fig.8 Maximum t_{rr} at $T_j = 25^\circ C$.

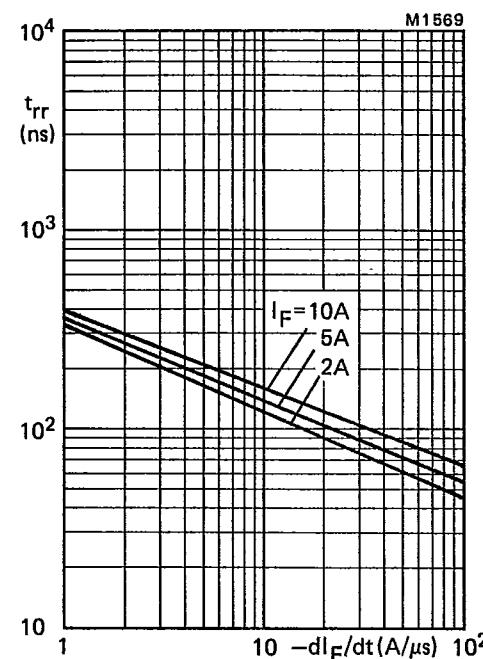


Fig.9 Maximum t_{rr} at $T_j = 100^\circ C$.

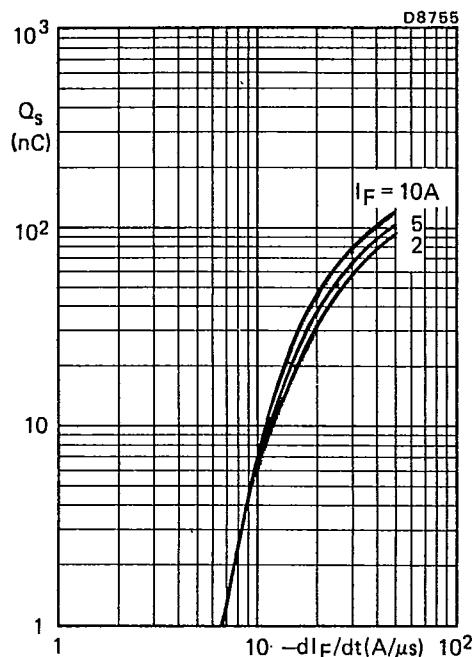


Fig.10 Maximum Q_s at $T_j = 25^\circ C$.

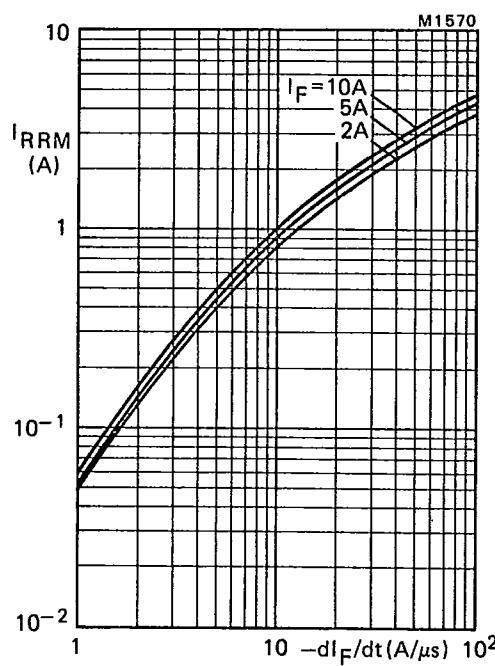
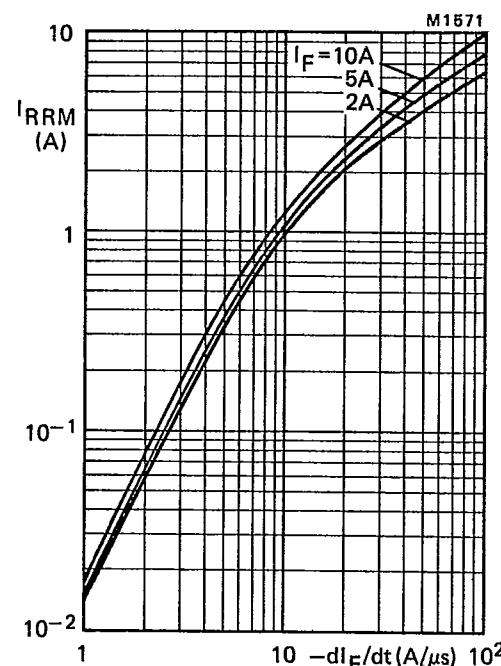
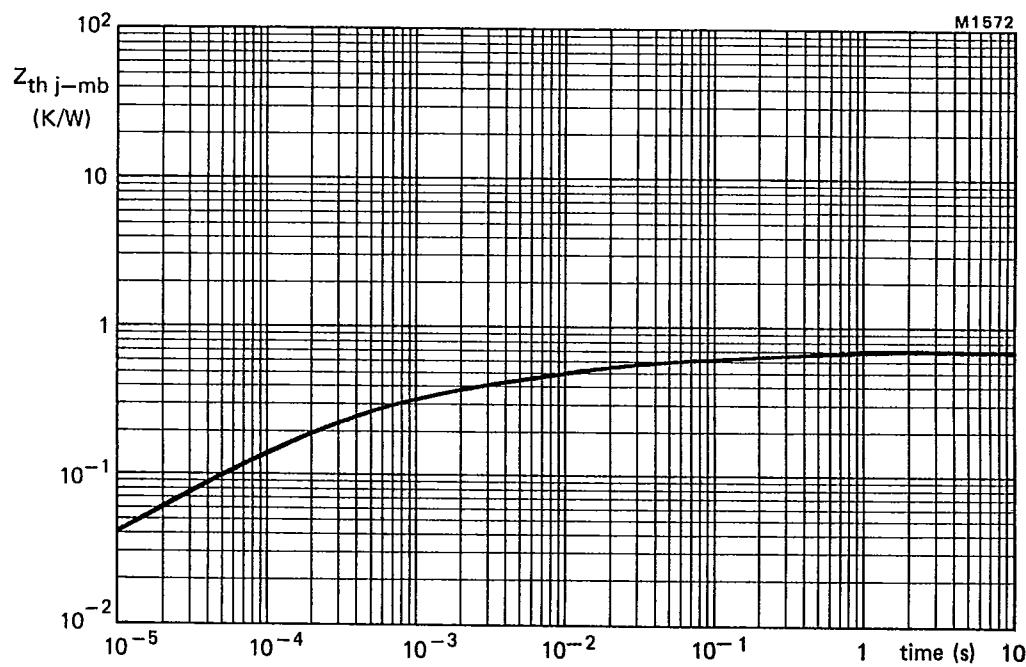
Fig.11 Maximum I_{RRM} at $T_j = 25$ °C.Fig.12 Maximum I_{RRM} at $T_j = 100$ °C.

Fig.13 Transient thermal impedance.